

# TinyLogic ULP-A 3-Input AND Gate

## NC7SV11

The NC7SV11 is a single 3-Input AND Gate in tiny footprint packages. The device is designed to operate for  $V_{CC} = 0.9\text{ V}$  to  $3.6\text{ V}$ .

### Features

- Designed for 0.9 V to 3.6 V  $V_{CC}$  Operation
- 1.7 ns  $t_{PD}$  at 3.3 V (Typ)
- Inputs/Outputs Over-Voltage Tolerant up to 3.6 V
- $I_{OFF}$  Supports Partial Power Down Protection
- Source/Sink 24 mA at 3.3 V
- Available in SC-88 and MicroPak™ Packages
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

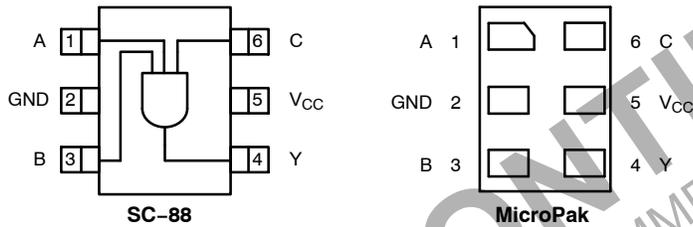


Figure 1. Pinout Diagrams (Top Views)



Figure 2. Logic Symbol

### PIN ASSIGNMENT

Pin	Function
1	A
2	GND
3	B
4	Y
5	$V_{CC}$
6	C

### FUNCTION TABLE (Y = ABC)

Inputs			Output
A	B	C	Y
X	X	L	L
X	L	X	L
L	X	X	L
H	H	H	H

H = HIGH Logic Level  
L = LOW Logic Level  
X = Either LOW or HIGH Logic Level



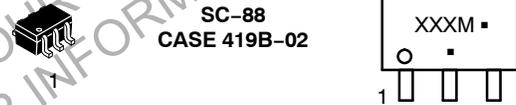
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### MARKING DIAGRAMS



CC = Specific Device Code  
KK = 2-Digit Lot Run Traceability Code  
XY = 2-Digit Date Code  
Z = Assembly Plant Code



XXX = Specific Device Code  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)  
\*Date Code orientation and/or position may vary depending upon manufacturing location.

### ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 6 of this data sheet.

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## MAXIMUM RATINGS

Symbol	Characteristics	Value	Unit
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +4.3	V
V <sub>IN</sub>	DC Input Voltage	-0.5 to +4.3	V
V <sub>OUT</sub>	DC Output Voltage Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to +4.3 -0.5 to +4.3	V
I <sub>IK</sub>	DC Input Diode Current V <sub>IN</sub> < GND	-50	mA
I <sub>OK</sub>	DC Output Diode Current V <sub>OUT</sub> < GND	-50	mA
I <sub>OUT</sub>	DC Output Source/Sink Current	±50	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC Supply Current per Supply Pin or Ground Pin	±50	mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
T <sub>J</sub>	Junction Temperature Under Bias	+150	°C
θ <sub>JA</sub>	Thermal Resistance (Note 2) SC-88 MicroPak	377 154	°C/W
P <sub>D</sub>	Power Dissipation in Still Air SC-88 MicroPak	332 812	mW
MSL	Moisture Sensitivity	Level 1	-
F <sub>R</sub>	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V <sub>ESD</sub>	ESD Withstand Voltage (Note 3) Human Body Model Charged Device Model	2000 1000	V
I <sub>Latchup</sub>	Latchup Performance (Note 4)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri-stated.
2. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow per JESD51-7.
3. HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.
4. Tested to EIA/JESD78 Class II.

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## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	0.9	3.6	V
V <sub>IN</sub>	DC Input Voltage	0	3.6	V
V <sub>OUT</sub>	DC Output Voltage Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	0	V <sub>CC</sub>	
		0	3.6	
		0	3.6	
T <sub>A</sub>	Operating Temperature Range	-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Transition Rise and Fall Time V <sub>CC</sub> = 3.3 V ± 0.3 V	0	10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Condition	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			T <sub>A</sub> = -40°C to +85°C		Unit
				Min	Typ	Max	Min	Max	
V <sub>IH</sub>	High-Level Input Voltage		0.9	-	0.5	-	-	-	V
			1.1 to 1.3	0.65 x V <sub>CC</sub>	-	-	0.65 x V <sub>CC</sub>	-	
			1.4 to 1.6	0.65 x V <sub>CC</sub>	-	-	0.65 x V <sub>CC</sub>	-	
			1.65 to 1.95	0.65 x V <sub>CC</sub>	-	-	0.65 x V <sub>CC</sub>	-	
			2.3 to <2.7	1.6	-	-	1.6	-	
			2.7 to 3.6	2.0	-	-	2.0	-	
V <sub>IL</sub>	Low-Level Input Voltage		0.9	-	0.5	-	-	-	V
			1.1 to 1.3	-	-	0.35 x V <sub>CC</sub>	-	0.35 x V <sub>CC</sub>	
			1.4 to 1.6	-	-	0.35 x V <sub>CC</sub>	-	0.35 x V <sub>CC</sub>	
			1.65 to 1.95	-	-	0.35 x V <sub>CC</sub>	-	0.35 x V <sub>CC</sub>	
			2.3 to <2.7	-	-	0.7	-	0.7	
			2.7 to 3.6	-	-	0.8	-	0.8	
V <sub>OH</sub>	High-Level Output Voltage	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>OH</sub> = -100 μA	0.9	-	V <sub>CC</sub> - 0.1	-	-	-	V
			1.1 to 1.3	V <sub>CC</sub> - 0.1	-	-	V <sub>CC</sub> - 0.1	-	
		1.4 to 1.6	V <sub>CC</sub> - 0.1	-	-	V <sub>CC</sub> - 0.1	-		
		1.65 to 1.95	V <sub>CC</sub> - 0.2	-	-	V <sub>CC</sub> - 0.2	-		
		2.3 to <2.7	V <sub>CC</sub> - 0.2	-	-	V <sub>CC</sub> - 0.2	-		
		2.7 to 3.6	V <sub>CC</sub> - 0.2	-	-	V <sub>CC</sub> - 0.2	-		
		I <sub>OH</sub> = -2 mA	1.1 to 1.3	0.75 x V <sub>CC</sub>	-	-	0.75 x V <sub>CC</sub>	-	
		I <sub>OH</sub> = -4 mA	1.4 to 1.6	0.75 x V <sub>CC</sub>	-	-	0.75 x V <sub>CC</sub>	-	
		I <sub>OH</sub> = -6 mA	1.65 to 1.95	1.25	-	-	1.25	-	
			2.3 to <2.7	2.0	-	-	2.0	-	
		I <sub>OH</sub> = -12 mA	2.3 to <2.7	1.8	-	-	1.8	-	
			2.7 to 3.6	2.2	-	-	2.2	-	
		I <sub>OH</sub> = -18 mA	2.3 to <2.7	1.7	-	-	1.7	-	
			2.7 to 3.6	2.4	-	-	2.4	-	
		I <sub>OH</sub> = -24 mA	2.7 to 3.6	2.2	-	-	2.2	-	

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## DC ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Condition	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			T <sub>A</sub> = -40°C to +85°C		Unit	
				Min	Typ	Max	Min	Max		
V <sub>OL</sub>	Low-Level Output Voltage	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>							V	
		I <sub>OL</sub> = 100 μA	0.9	-	0.1	-	-	-		-
			1.1 to 1.3	-	-	0.1	-	0.1		-
			1.4 to 1.6	-	-	0.1	-	0.1		-
			1.65 to 1.95	-	-	0.2	-	0.2		-
			2.3 to < 2.7	-	-	0.2	-	0.2		-
			2.7 to 3.6	-	-	0.2	-	0.2		-
		I <sub>OL</sub> = 2 mA	1.1 to 1.3	-	-	0.25 x V <sub>CC</sub>	-	0.25 x V <sub>CC</sub>		-
		I <sub>OL</sub> = 4 mA	1.4 to 1.6	-	-	0.25 x V <sub>CC</sub>	-	0.25 x V <sub>CC</sub>		-
		I <sub>OL</sub> = 6 mA	1.65 to 1.95	-	-	0.3	-	0.3		-
			2.3 to < 2.7	-	-	0.4	-	0.4		-
		I <sub>OL</sub> = 12 mA	2.7 to 3.6	-	-	0.4	-	0.4		-
			2.3 to < 2.7	-	-	0.6	-	0.6		-
I <sub>OL</sub> = 18 mA	2.7 to 3.6	-	-	0.4	-	0.4	-			
	2.3 to < 2.7	-	-	0.6	-	0.6	-			
I <sub>OL</sub> = 24 mA	2.7 to 3.6	-	-	0.55	-	0.55	-			
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 0 V to 3.6 V	0.9 to 3.6	-	-	±0.1	-	±0.5	μA	
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 0 V to 3.6 V or V <sub>OUT</sub> = 0 V to 3.6 V	0	-	-	0.5	-	0.5	μA	
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	0.9 to 3.6	-	-	0.9	-	0.9	μA	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## AC ELECTRICAL CHARACTERISTICS

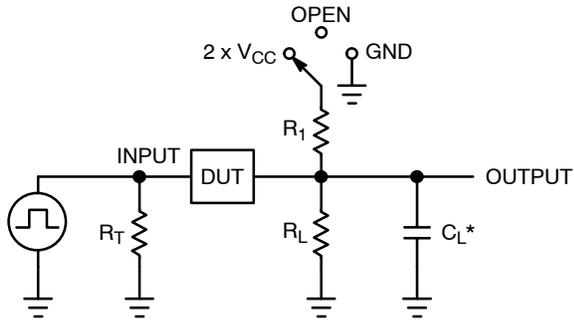
Symbol	Parameter	Condition	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			T <sub>A</sub> = -40°C to +85°C		Unit
				Min	Typ	Max	Min	Max	
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay, (A or B or C) to Y (Figures 3 and 4)	R <sub>L</sub> = 1 MΩ, C <sub>L</sub> = 15 pF	0.9	-	14.4	-	-	-	ns
		R <sub>L</sub> = 2 kΩ, C <sub>L</sub> = 15 pF	1.1 to 1.3	-	5.0	17.0	-	19.2	
			1.4 to 1.6	-	3.2	10.2	-	12.0	
		R <sub>L</sub> = 500 Ω, C <sub>L</sub> = 30 pF	1.65 to 1.95	-	2.7	7.8	-	9.2	
			2.3 to 2.7	-	2.0	5.2	-	5.9	
			2.7 to 3.6	-	1.7	4.5	-	4.8	

## CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Condition	Typical (T <sub>A</sub> = 25°C)	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>CC</sub> = 0 V	2.0	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>CC</sub> = 0 V	4.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 5)	f = 10 MHz, V <sub>CC</sub> = 0.9 to 3.6 V, V <sub>IN</sub> = 0 V or V <sub>CC</sub>	8.0	pF

5. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no-load dynamic power consumption: P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

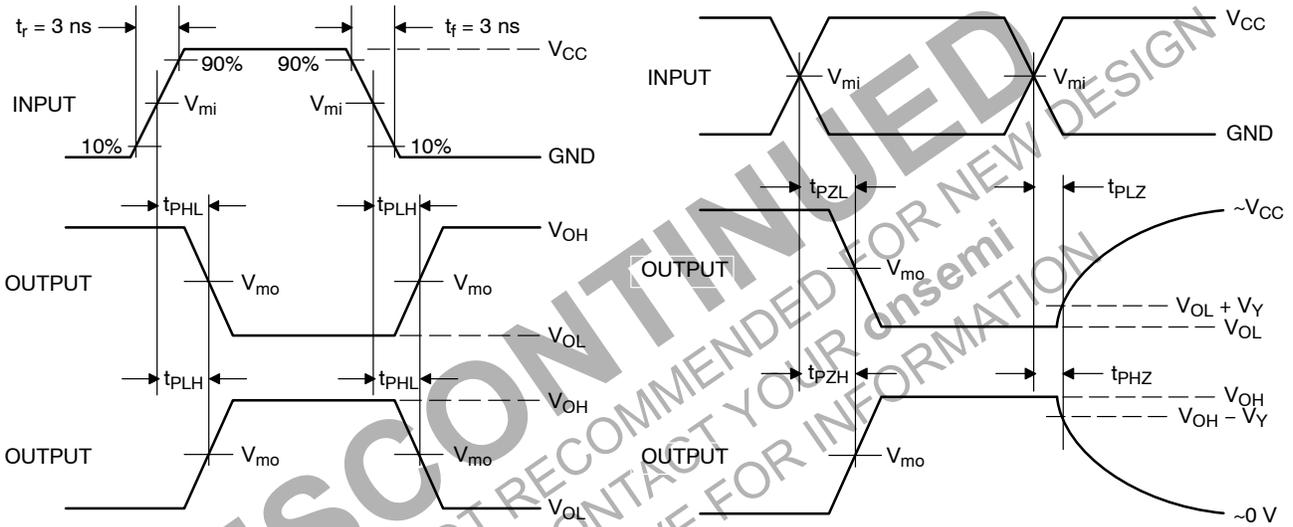
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$C_L$  includes probe and jig capacitance  
 $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50  $\Omega$ )  
 $f = 1$  MHz

Test	Switch Position
$t_{PLH} / t_{PHL}$	Open
$t_{PLZ} / t_{PZL}$	$2 \times V_{CC}$
$t_{PHZ} / t_{PZH}$	GND

Figure 3. Test Circuit



$V_{CC}, V$	$V_{mi}, V$	$V_{mo}, V$	$V_Y, V$
0.9	$V_{CC} / 2$	$V_{CC} / 2$	0.1
1.1 to 1.3	$V_{CC} / 2$	$V_{CC} / 2$	0.1
1.4 to 1.6	$V_{CC} / 2$	$V_{CC} / 2$	0.1
1.65 to 1.95	$V_{CC} / 2$	$V_{CC} / 2$	0.15
2.3 to 2.7	$V_{CC} / 2$	$V_{CC} / 2$	0.15
3.0 to 3.6	1.5	1.5	0.3

Figure 4. Switching Waveforms

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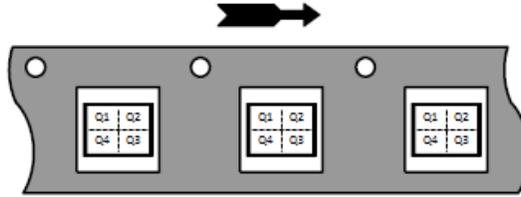
## ORDERING INFORMATION

Device	Package	Marking	Pin 1 Orientation (See below)	Shipping <sup>†</sup>
NC7SV11P6X	SC-88	V11	Q4	3000 / Tape & Reel
NC7SV11L6X	MicroPak	AT	Q4	5000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### Pin 1 Orientation in Tape and Reel

Direction of Feed



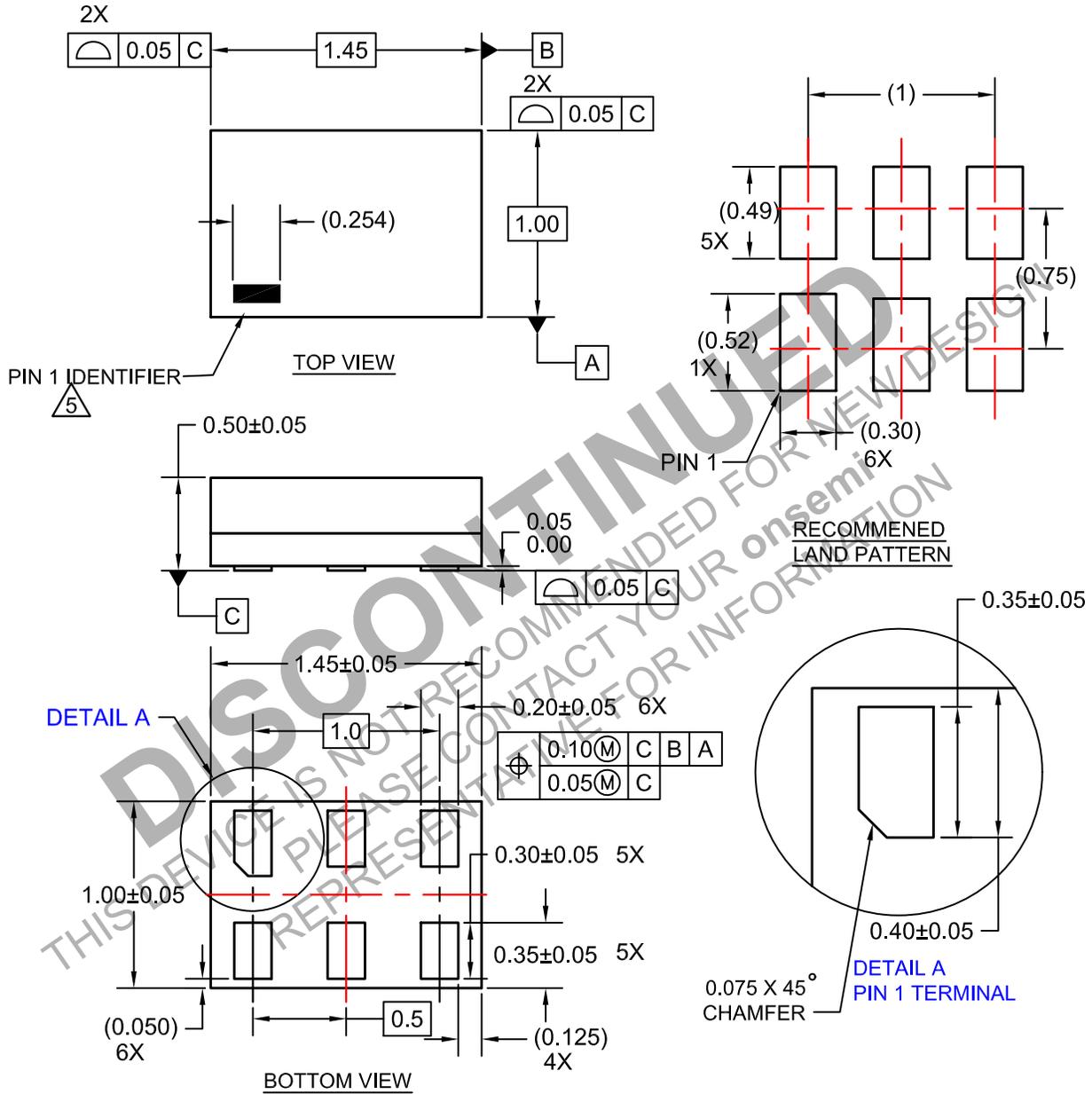
**DISCONTINUED**  
THIS DEVICE IS NOT RECOMMENDED FOR NEW DESIGN  
PLEASE CONTACT YOUR onsemi  
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## PACKAGE DIMENSIONS

SIP6 1.45X1.0  
CASE 127EB  
ISSUE O



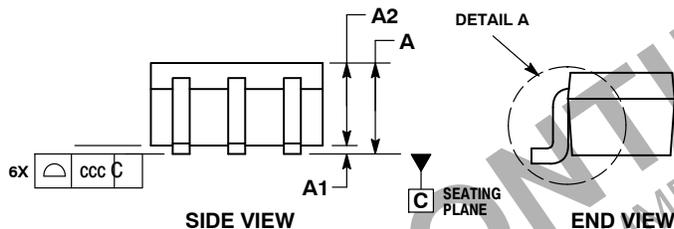
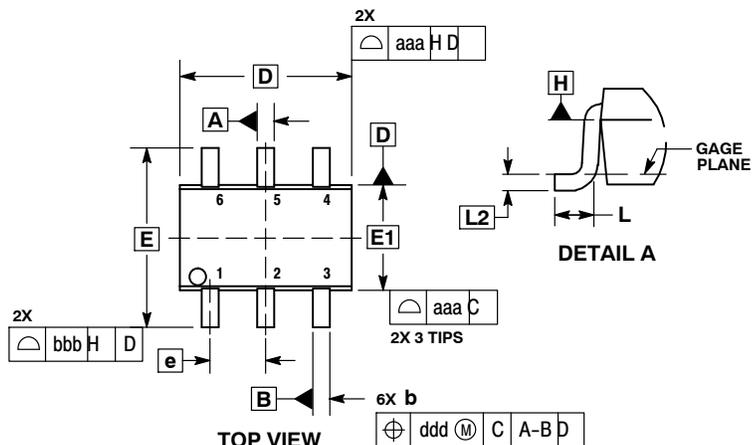
**NOTES:**

1. CONFORMS TO JEDEC STANDARD MO-252 VARIATION UAAD
2. DIMENSIONS ARE IN MILLIMETERS
3. DRAWING CONFORMS TO ASME Y14.5M-2009
4. PIN ONE IDENTIFIER IS 2X LENGTH OF ANY OTHER LINE IN THE MARK CODE LAYOUT.

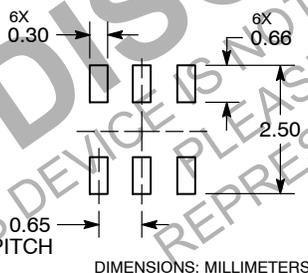
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## PACKAGE DIMENSIONS

SC – 88/SC70 – 6/SOT – 363  
CASE 419B – 02  
ISSUE Y



### RECOMMENDED SOLDERING FOOTPRINT\*



#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END.
4. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AND DATUM H.
5. DATUMS A AND B ARE DETERMINED AT DATUM H.
6. DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.
7. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION b AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	—	—	1.10	—	—	0.043
A1	0.00	—	0.10	0.000	—	0.004
A2	0.70	0.90	1.00	0.027	0.035	0.039
b	0.15	0.20	0.25	0.006	0.008	0.010
C	0.08	0.15	0.22	0.003	0.006	0.009
D	1.80	2.00	2.20	0.070	0.078	0.086
E	2.00	2.10	2.20	0.078	0.082	0.086
E1	1.15	1.25	1.35	0.045	0.049	0.053
e	0.65 BSC			0.026 BSC		
L	0.26	0.36	0.46	0.010	0.014	0.018
L2	0.15 BSC			0.006 BSC		
aaa	0.15			0.006		
bbb	0.30			0.012		
ccc	0.10			0.004		
ddd	0.10			0.004		

\*For additional information on our Pb – Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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